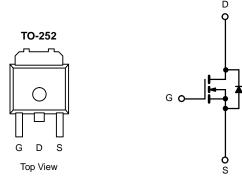


#### DTU130N06 www.din-tek.jp

# N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A) <sup>a, e</sup>	Q <sub>g</sub> (Typ)			
60	0.0029 at V <sub>GS</sub> = 10 V	130	65 nC			
	0.0039 at V <sub>GS</sub> = 4.5 V	110	05 110			
<u>.</u>						



#### **FEATURES**

- **DT-Trench Power MOSFET** •
- ٠
- 100 % R<sub>g</sub> and UIS Tested Compliant to RoHS Directive 2011/65/EU •

#### **APPLICATIONS**

- OR-ing
- Server
- DC/DC

Parameter		Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20	v
	T <sub>C</sub> = 25 °C		130 <sup>a, e</sup>	
Continuous Drain Current (T <sub>J</sub> = 175 °C)	T <sub>C</sub> = 70 °C		112 <sup>e</sup>	
Continuous Drain Current (1j = 173 C)	T <sub>A</sub> = 25 °C	I <sub>D</sub>	33.2 <sup>b, c</sup>	A
	T <sub>A</sub> = 70 °C		29.3 <sup>b, c</sup>	
Pulsed Drain Current		I <sub>DM</sub>	480	
Avalanche Current Pulse		I <sub>AS</sub>	46	
Single Pulse Avalanche Energy	Energy L = 0.1 mH		240	mJ
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C		130 <sup>a, e</sup>	A
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	4.12 <sup>b, c</sup>	
	T <sub>C</sub> = 25 °C		180 <sup>a</sup>	
Maximum Dawar Dissipation	T <sub>C</sub> = 70 °C	P <sub>D</sub>	130	w
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	' D	3.78 <sup>b, c</sup>	vv
	T <sub>A</sub> = 70 °C		2.72 <sup>b, c</sup>	
Operating Junction and Storage Temperature Ra	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175	°C	

N-Channel MOSFET

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Тур.	Max.	Unit	
Maximum Junction-to-Ambient <sup>b, d</sup>	$t \le 10 \text{ sec}$	R <sub>thJA</sub>	14	20	°C/W	
Maximum Junction-to-Case	Steady State	R <sub>thJC</sub>	0.5	0.6	0,10	

Notes:

a. Based on  $T_C = 25 \text{ °C}$ . b. Surface mounted on 1" x 1" FR4 board.

b. Surface mounted on the control board.
c. t = 10 sec.
d. Maximum under steady state conditions is 90 °C/W.
e. Calculated based on maximum junction temperature. Package limitation current is 85 A.



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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_{D} = 250 \mu A$	60			V	
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I <sub>D</sub> = 250 μA		35		mV/°C	
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 7.5			
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.2		2.5	V	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	lace	V <sub>DS</sub> = 32 V, V <sub>GS</sub> = 0 V			1		
Zero Gale voltage Drain Current	IDSS	$V_{DS}$ = 32 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			10	μA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5$ V, $V_{GS} = 10$ V	130			А	
	P	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 30 A	0.0029 0.004		0.0040		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.0039	0.0050	50 Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 32V, I_{D} = 30 A$		50		S	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			3945		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 0 V, f = 1 MHz		712			
Reverse Transfer Capacitance	C <sub>rss</sub>			30			
T ( ) O ( )		$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$		65	79	79 100 nC	
Total Gate Charge	Qg			50.2	100		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 30 A		11			
Gate-Drain Charge	Q <sub>gd</sub>			9			
Gate Resistance	Rg	f = 1 MHz		1.2	1.8	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			10	18		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 0.625 $\Omega$		5	10	-	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D} \cong$ 30 A, $\text{V}_\text{GEN}$ = 10 V, $\text{R}_\text{g}$ = 1 $\Omega$		35	65		
Fall Time	t <sub>f</sub>			6	11		
Turn-On Delay Time	t <sub>d(on)</sub>			32	46	ns	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, R <sub>L</sub> = 0.67 $\Omega$		102	186	-	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong$ 20 A, $V_{GEN}$ = 4.5 V, $R_g$ = 1 $\Omega$		33	55		
Fall Time	t <sub>f</sub>			10	16		
Drain-Source Body Diode Characteristic							
Continuous Source-Drain Diode Current	ا <sub>S</sub>	T <sub>C</sub> = 25 °C			130		
Pulse Diode Forward Current <sup>a</sup>	I <sub>SM</sub>			1	480	A	
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = 22 A		0.8	1.2	V	
Body Diode Reverse Recovery Time	t <sub>rr</sub>	-		22	28	ns	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>			52	66	nC	
Reverse Recovery Fall Time	ta	$I_F = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 \text{ °C}$		26			
Reverse Recovery Rise Time	t <sub>b</sub>			25		ns	

Notes:

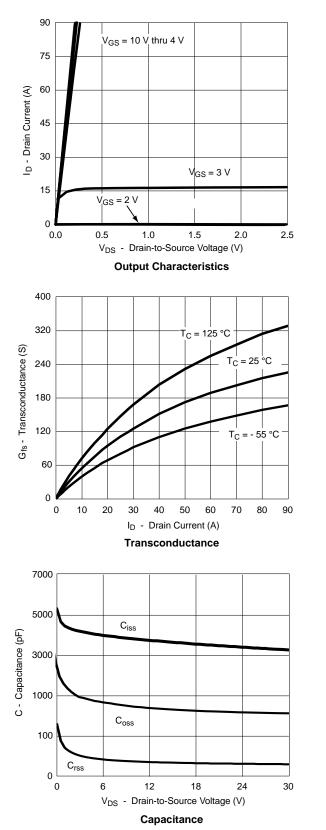
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

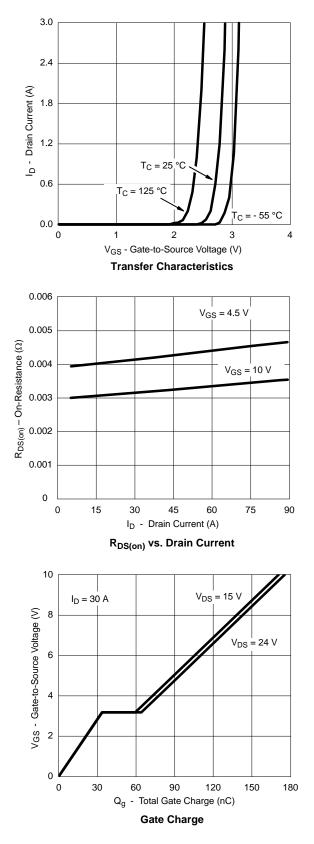
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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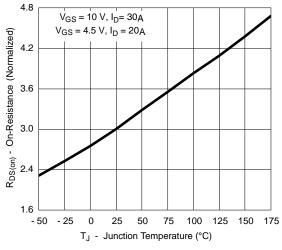
#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



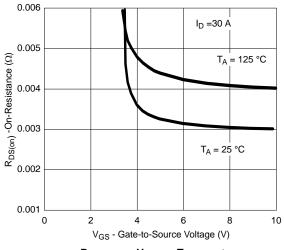


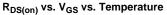
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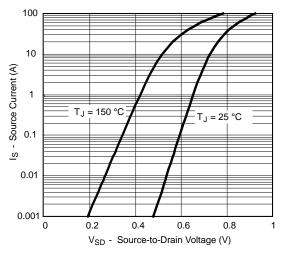
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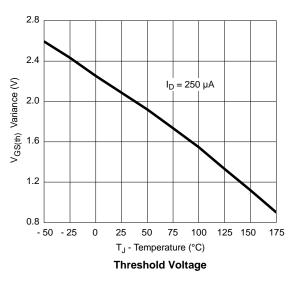


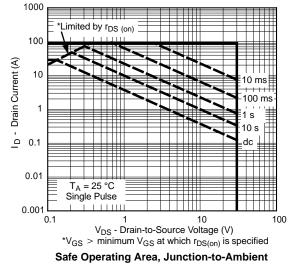






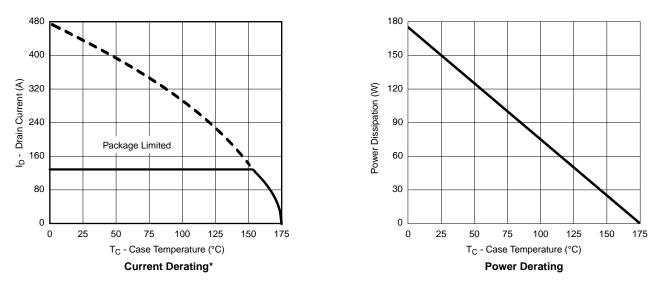




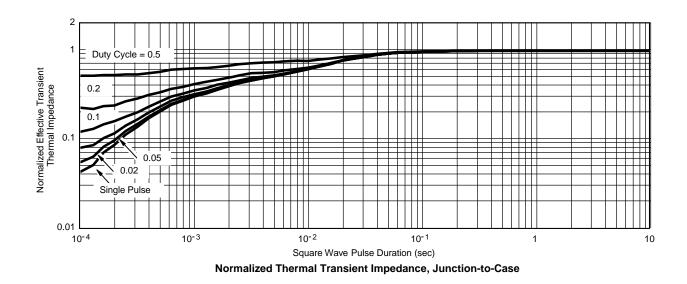


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#### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

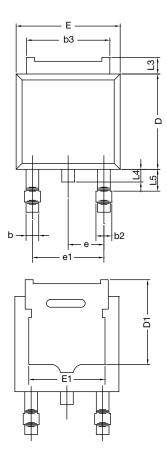


\*The power dissipation  $P_D$  is based on  $T_{J(max)} = 175$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.











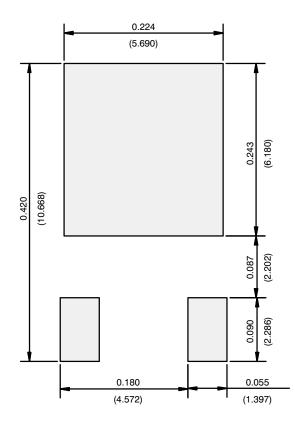
	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090	BSC	
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
ECN: X12-0247-Rev. M, 24-Dec-12 DWG: 5347					

#### Note

• Dimension L3 is for reference only.



#### **RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)**



Recommended Minimum Pads Dimensions in Inches/(mm)

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